

## 50 dB Gain, 43 dBm P1dB High Power GaN Amplifier at 100 Watt Psat Operating from 500 MHz to 2.5 GHz with SMA



### FMAM5060

#### Features

- GaN Design
- 500 MHz to 2.5 GHz Frequency Range
- P1dB: 43 dBm
- Psat 100 Watts typ
- Power Gain: 50 dB min
- Power Added Efficiency: 27%
- Gain Flatness  $\pm 2$  dB typ
- Enable with TTL Logic Control
- Current and Temperature Sense Functions
- 50 Ohms Input and Output Matched
- Instantaneous ultra broadband
- Built-in control and protection circuits
- D-Sub Control Connector with Mating Female Connector
- Optional Heatsink Available: Model FMAMG5068F

#### Applications

- Military Radio
- Communication Systems
- High Gain Driver Power Amplifier
- EMC Applications
- Test and Measurement applications

#### Description

The FMAM5060 is a high power amplifier that operates from 500 MHz to 2.5 GHz and generates 100 watts of saturated output power. The module utilizes GaN and chip-and-wire technology in the manufacturing process that ensures state-of-the-art power performance with excellent power-to-volume ratio that's ideal for broadband high power linear applications. This Class AB amplifier is designed for a 50 ohm input/output impedance and offers high efficiency and high linearity, operating over a wide dynamic range with impressive typical performance that includes 50 dB gain, 43 dBm P1dB, 27% power added efficiency,  $\pm 2$  dB gain flatness, -10 dBc harmonic suppression, -60 dBc Spurious, and a maximum input power level of +10 dBm. Typical DC bias requirements include +28V and 13A of current. The module uses an SMA female input and output connector. The DC interface incorporates a D-Sub 9 pin male connector for DC bias, Enable with TTL logic control, Current Sense, and Temperature Sense functions. A mating female D-SUB socket connector is included. The rugged amplifier design operates over wide temperature range from -20°C and +55°C and can withstand relative humidity exposure up to 95% maximum. An available heatsink with cooling fan (model PE15G5068F) is recommended to maintain an optimum baseplate temperature during operation.

#### Electrical Specifications (TA = +25°C, DC Voltage = +28Volts, DC Current = 13A)

Description	Min	Typ	Max	Unit
Frequency Range	0.5		2.5	GHz
Small Signal Gain		50		dB
Gain Flatness		$\pm 2$		dB
Pout at Sat.	+47.8	+50		dBm
Efficiency (PAE)		27		
Output Power at 1 dB Compression Point		+43		dBm
Harmonics @70 Watts		-10	-8	dBc
Spurious		-60		dBc
Impedance (Input)		50		Ohms
Impedance (Output)		50		Ohms
Input VSWR			3:1	
Input Return Loss			-10	dB
Operating DC Voltage	+24	+28	+32	Volts
Operating DC Current @100 Watts		13		A

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**Electrical Specifications** (TA = +25°C, DC Voltage = +28Volts, DC Current = 13A)

Description	Min	Typ	Max	Unit
OFF/ON Switch Time (10% to 90%)*		5		µs
Operating Temperature Range	-20		+60	°C

Electrical Specification Notes:  
Allow for 20% Increased DC Current during initial power-up stage. \*@1 kHz TTL

### Absolute Maximum Rating

Parameter	Rating
Input RF drive level without damage	+10 dBm (MAX)
Load VSWR @ Pout = 70 W	∞ @ all load phase & amplitude for duration of 1 minute; 3:1 @ all load phase & amplitude continuous
Over Temperature	85°C @ heatsink [restored @ 60°C]



ESD Sensitive Material,  
Transport material in  
Approved ESD bags. Handle  
only in approved  
ESD Workstation.

### Mechanical Specifications

#### Size

Length	7.08 in [179.83 mm]
Width	3.54 in [89.92 mm]
Height	0.98 in [24.89 mm]
Weight	2.64 lbs [1.2 kg]
Input Connector	SMA Female
Output Connector	SMA Female
Bias Connector	9-Pin D-Subminiature Male

### Environmental Specifications

#### Temperature

Operating Range	-20 to +60 deg C
Storage Range	-25 to +65 deg C
Humidity	95% Non-Condensing
Shock	Normal Truck Transport
Vibration	Normal Truck Transport

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**Compliance Certifications** (see [product page](#) for current document)

### Plotted and Other Data

Notes:

- Values at 25 °C, sea level
- Heatsink Required for Proper Operation Recommended Model: FMAMG5060F

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### Amplifier Power-up Precautions

- 1.) Confirm that proper ESD precautions and controls are always in place before handling any Amplifier module.
- 2.) Confirm adequate thermal management is in place to effectively dissipate heat away from the Amplifier package. The Amplifier operational baseplate temperature must be within the operational temperature range stated in the Amplifier datasheet. Depending on the design and thermal requirements, using a heatsink with cooling fan is always recommended for safe reliable operation. A heat sink without a cooling fan may also be used. Damage caused from overheating will void the warranty.
- 3.) Confirm adequate system grounding is established. The DC power supply and Amplifier must have a common ground in order to operate properly.
- 4.) Power Amplifiers may require additional DC Current when initially powered-up. Depending on the design, the input current draw could range from an additional 10% to 100% above the maximum rated DC current of the Amplifier. This varies based on product part number.
- 5.) Confirm the DC power supply, if limited, is set to allow for additional start-up current that's rated for the Power Amplifier.
- 6.) Confirm the system is designed and calibrated for 50 ohms. Any impedance mismatch may cause performance issues.
- 7.) Perform a CALIBRATION (if required) with the loads before connecting the Amplifier to the Network Analyzer to ensure proper performance.
- 8.) Use a fixed attenuator between the signal source and input port of the Amplifier to optimize the input VSWR match.
- 9.) Confirm the input power level at the input port of the amplifier does not exceed the maximum rated limit for input power (as stated in the Amplifier datasheet).
  - $P_{in}$  for Small Signal Gain = P1dB-SSG-10 dB
  - $P_{in}$  for P1dB = P1dB-SSG+1 dB
- 10.) Confirm the Network Analyzer is always connected to the Amplifier first before DC power is applied to the Amplifier.
- 11.) As long as the input and output ports of the amplifier are connected to a 50Ohm load and RF signal power is applied, the Amplifier can be powered up with DC voltage.
- 12.) Confirm the Amplifier output load is matched for a 50 Ohm impedance and will not exceed the maximum rated VSWR or Return Loss limit for the Amplifier. Exceeding the maximum rated VSWR or Return Loss limit will result in reflected signal power that could damage the Amplifier and void the warranty.
- 13.) **Power Amplifier connected to an Antenna for signal transmission** - It's strongly recommended to use a high power fixed attenuator pad or an Isolator between the output port of the Amplifier and input port to the antenna. Any reflected signal power due to impedance mismatch will likely damage the Amplifier and void the warranty.
- 14.) The attenuator or isolator used at the output port of the Amplifier must be rated to handle the output power level and operational frequency band of the amplifier.

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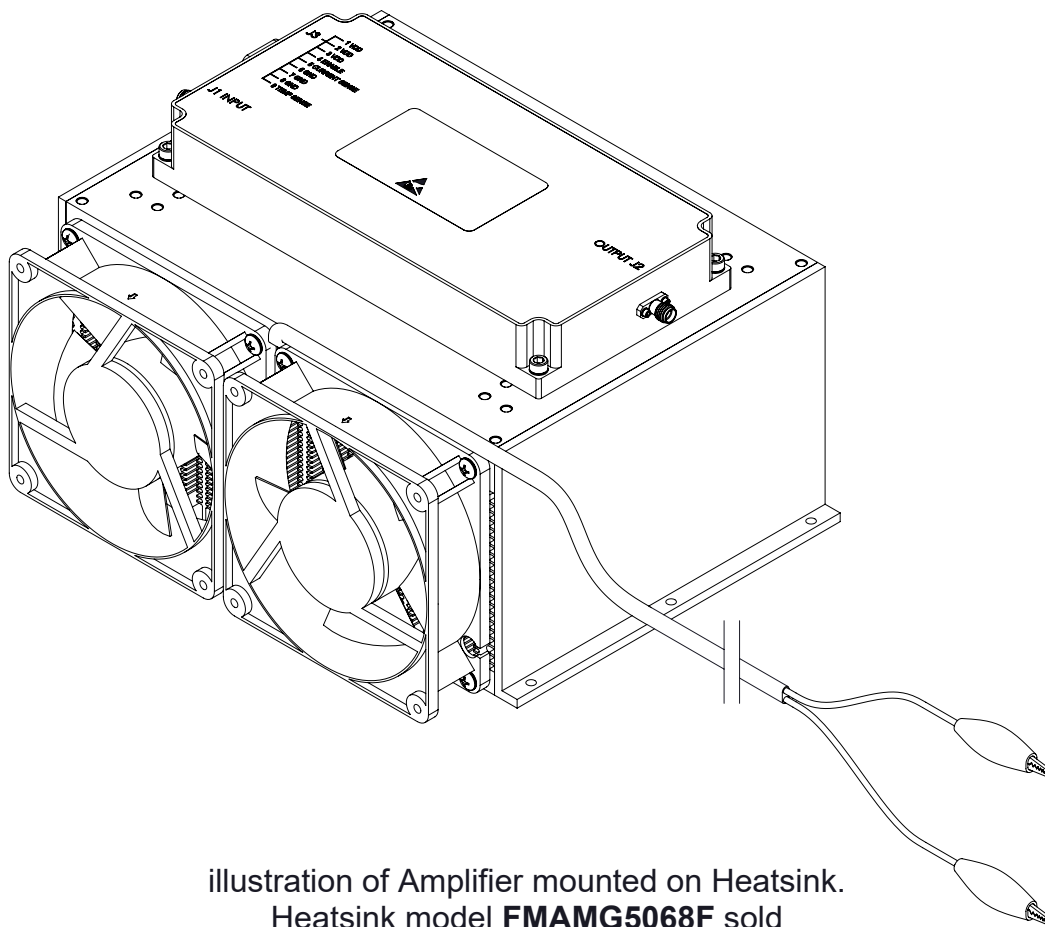


illustration of Amplifier mounted on Heatsink.  
Heatsink model **FMAMG5068F** sold  
separately.(Picture shown for Reference Only)

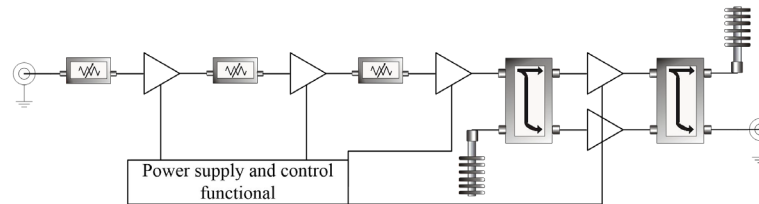
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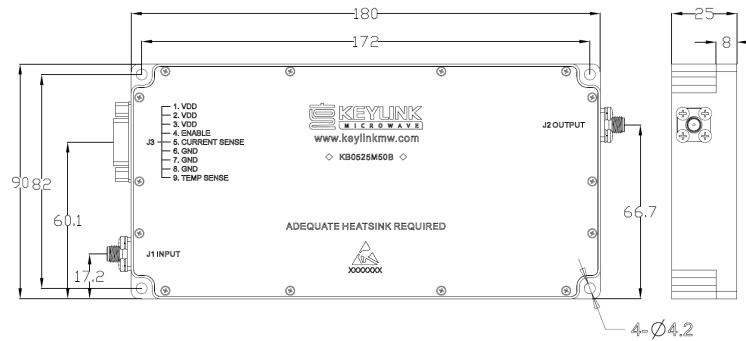
**FMAM5060**

**Functional Block Diagram**

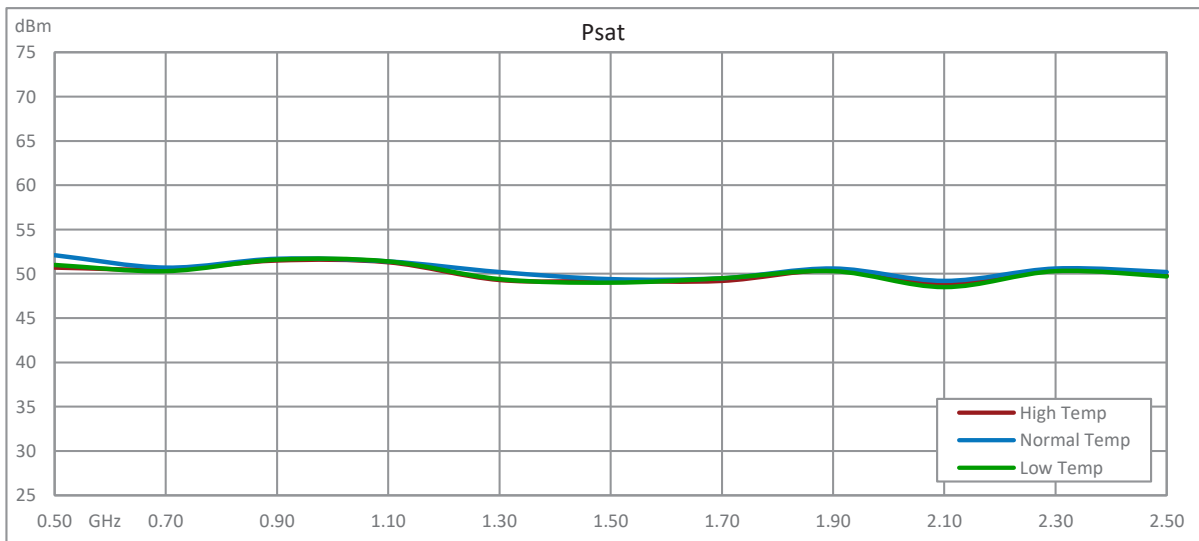
Functional Diagram



OUTLINE DRAWING (All dimensions in mm [inch])



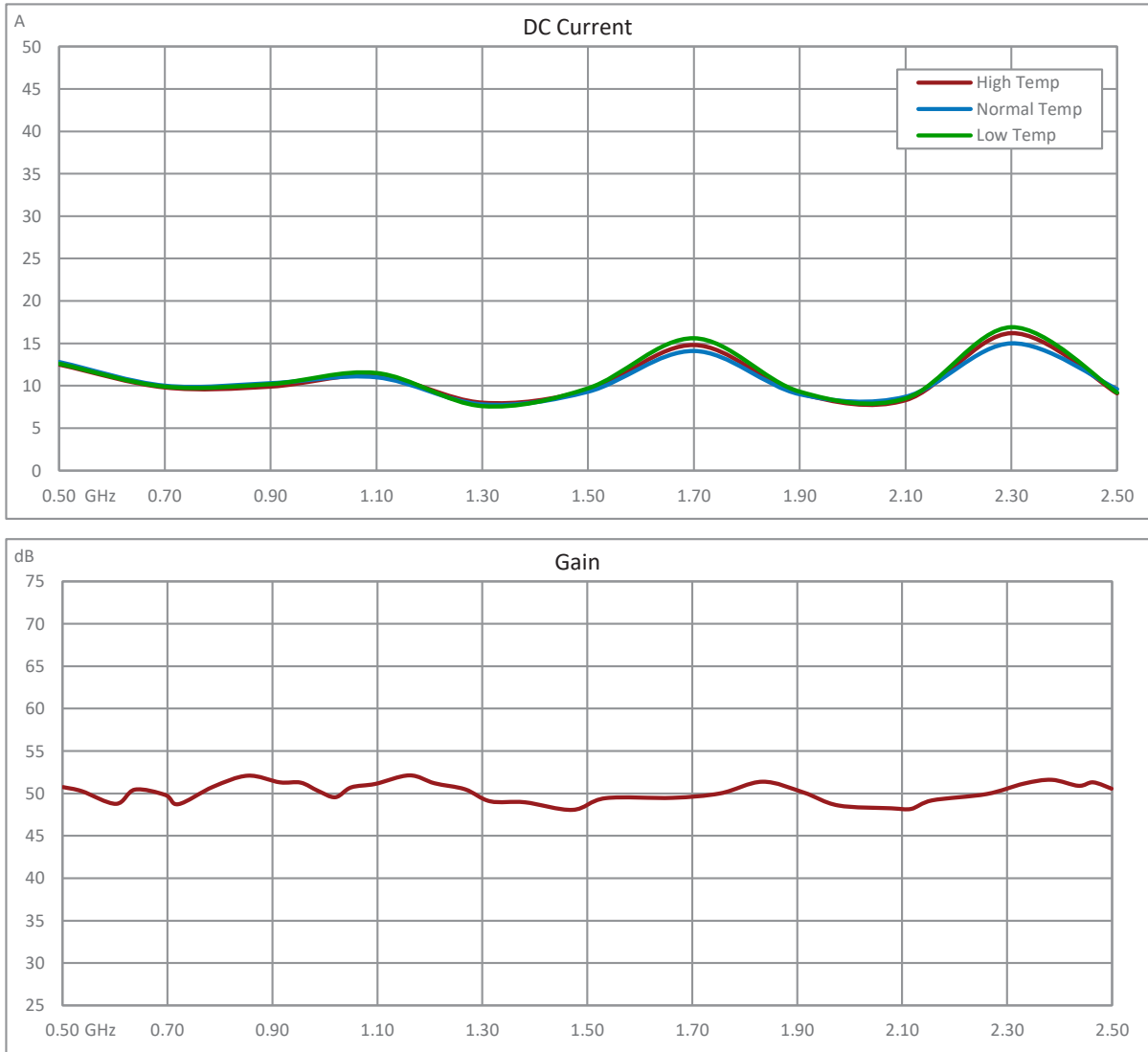
**Typical Performance Data**



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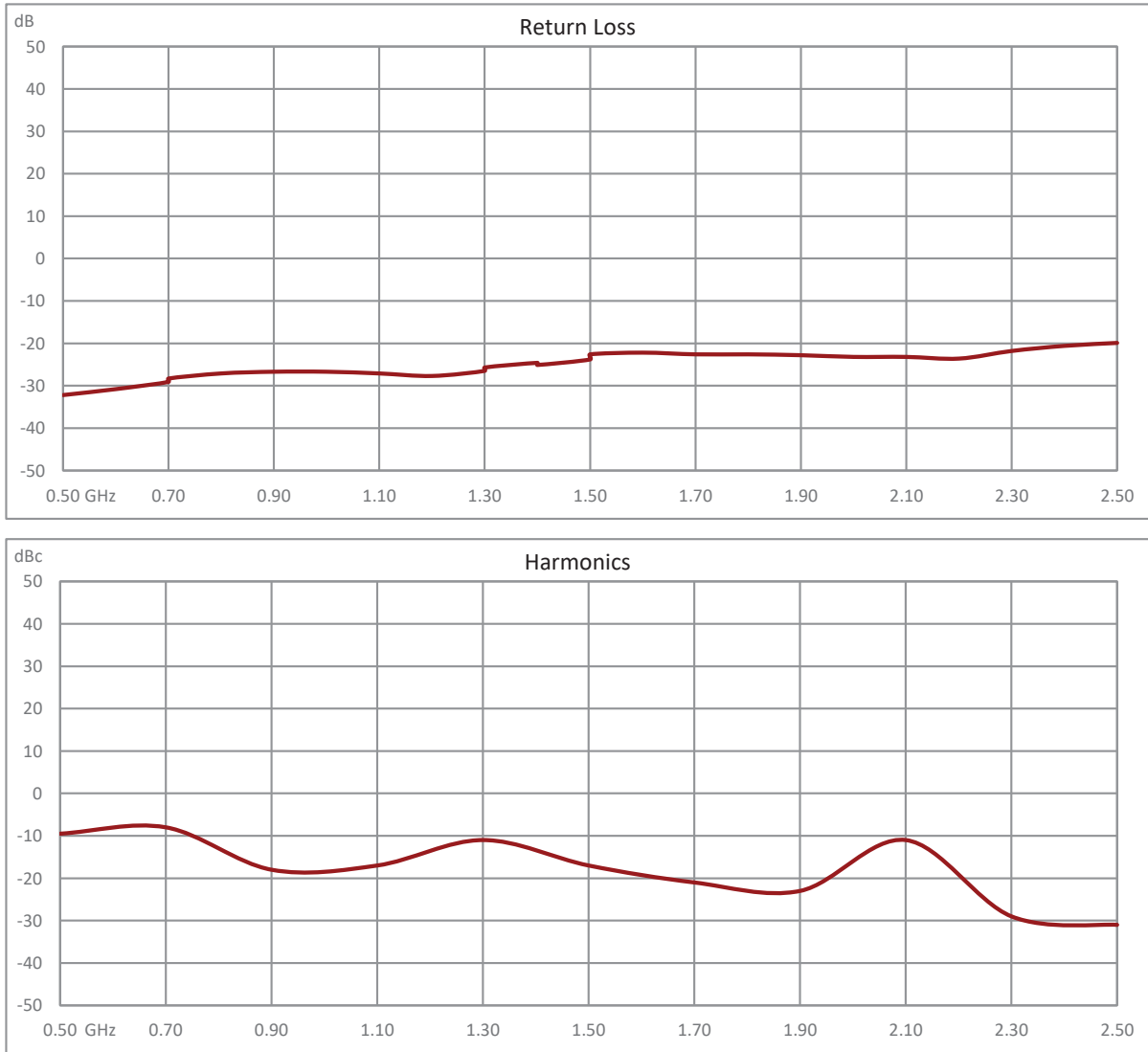
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50 dB Gain, 43 dBm P1dB High Power GaN Amplifier at 100 Watt Psat Operating from 500 MHz to 2.5 GHz with SMA from Fairview Microwave is in-stock and available to ship same-day. All of our RF/microwave products are available off-the-shelf from our ISO 9001:2008 certified facilities in Lewisville, Texas. Fairview Microwave is RF on-demand.

For additional information on this product, please click the following link: [50 dB Gain, 43 dBm P1dB High Power GaN Amplifier at 100 Watt Psat Operating from 500 MHz to 2.5 GHz with SMA FMAM5060](https://www.fairviewmicrowave.com/high-power-amplifier-100watt-fmam5060-p.aspx)

URL: <https://www.fairviewmicrowave.com/high-power-amplifier-100watt-fmam5060-p.aspx>



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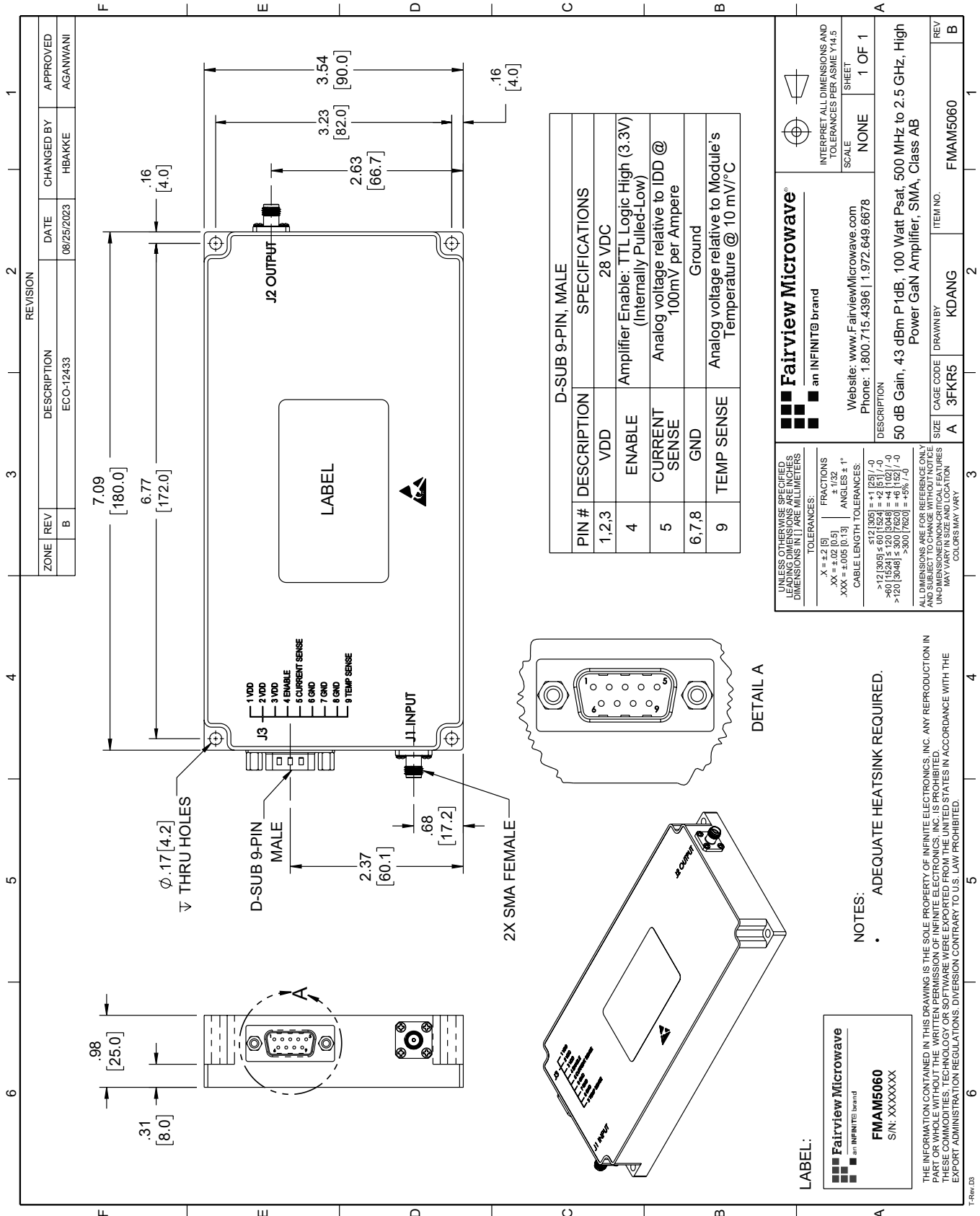
For additional information on this product, please click the following link: [50 dB Gain, 43 dBm P1dB High Power GaN Amplifier at 100 Watt Psat Operating from 500 MHz to 2.5 GHz with SMA FMAM5060](#)

URL: <https://www.fairviewmicrowave.com/high-power-amplifier-100watt-fmam5060-p.aspx>

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# FMAM5060 CAD Drawing

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 Phone: 1.800.715.4396 | 1.972.649.6678

INTERPRET ALL DIMENSIONS AND TOLERANCES PER ASME Y14.5

SCALE: NONE  
 SHEET: 1 OF 1

DESCRIPTION: 50 dB Gain, 43 dBm P1dB, 100 Watt Psat, 500 MHz to 2.5 GHz, High Power GaN Amplifier, SMA, Class AB

ITEM NO: FMAM5060

REV: B

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**FMAM5060**  
 S/N: XXXXXXXX

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NOTES:  
 • ADEQUATE HEATSINK REQUIRED.

T-Rev: D3